

40 SERIES

HIGH VOLTAGE ▲ Si MOSFET RELAY

SILICON Si MOSFET RELAY ▲ DIP and SMD type

Switches AC or DC load

1500V load voltage

Input TTL / CMOS compatible








Moisture Sensitivity Level ▲ MSL 1

 **UL 1577 approved ▲ File no E344988**

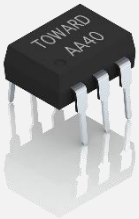
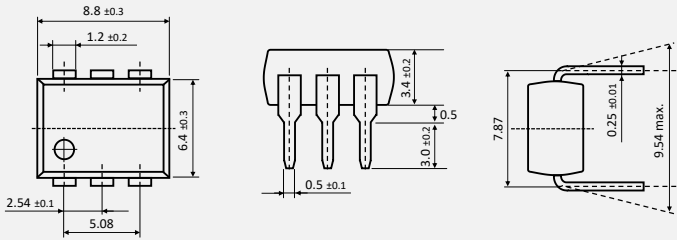
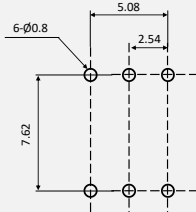

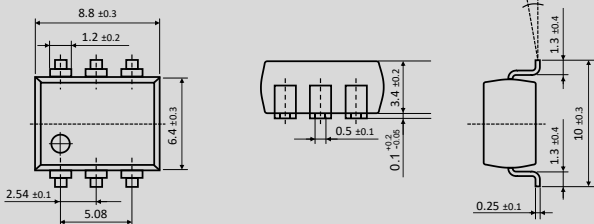
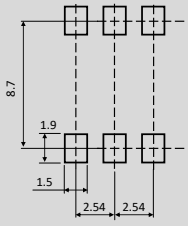
SPECIFICATION

Item		Characteristics
Contact Form		1 Form A ▲ Normally open switch
Load Voltage	V_L	1500V
Operation LED Current	$I_{F\ ON}$	5mA
Load Current	I_L	45mA
On-Resistance	R_{ON}	180Ω
Output Capacitance	C_{OUT}	83pF
Low Off-State Leakage Current	I_{LEAK}	10μA at 1500V _{DC}

APPLICATIONS

Automatic Test Equipment	I/O Modules	Industrial Automation	Measurement Equipment	Security Equipment	Sensing Equipment	Telecom Equipment
						

DIMENSIONS

Package	Illustration	Dimensions	PCB Board Pattern
DIP-6			 <p>BOTTOM VIEW</p>
SMD-6			 <p>TOP VIEW</p>

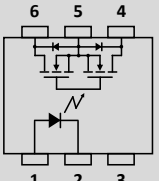
ABSOLUTE MAXIMUM RATINGS ▲ AMBIENT TEMPERATURE $T_A = 25^\circ\text{C}$

Item	Condition	Symbol	Value		Unit
Type	Outline package		DIP-6	SMD-6	
	Part number		AA40	AA40F	
	Output channels		1	1	Channel
Input	Continuous LED Current	I_F	50		mA
	Peak LED Current	I_{FP}	500		mA
	LED Reverse Voltage	V_R	5		V
	Input Power Dissipation	P_{IN}	75		mW
Output	Load Voltage	V_L	1500 (AC peak or DC)		V
	Load Current	Connecting A	45 (AC or DC)		mA
		Connecting B	50 (DC)		
		Connecting C	70 (DC)		
	Peak Load Current	I_{PEAK}	180		mA
	Output Power Dissipation	P_{OUT}	450		mW
Relay	Total Power Dissipation	P_T	500		mW
	I/O Breakdown Voltage	$V_{I/O}$	3750		V_{RMS}
	I/O Breakdown Voltage (Suffix-H)	$V_{I/O}$	5000		V_{RMS}
	Operating Temperature Range	T_{OPR}	-40 to +85		$^\circ\text{C}$
	Storage Temperature Range	T_{STG}	-40 to +100		$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS ▲ AMBIENT TEMPERATURE $T_A = 25^\circ\text{C}$

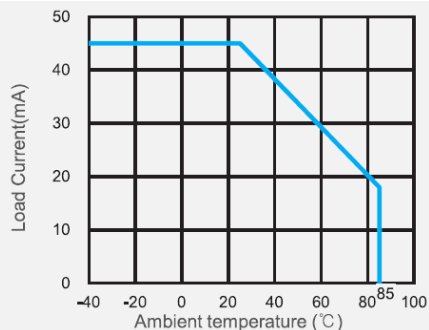
Item		Condition	Symbol	Min.	Typ.	Max.	Unit
Input	LED Forward Voltage	I _F = 10mA	V _F	1	1.17	1.5	V
	Operation LED Current		I _{F ON}		0.8	5	mA
	Recovery LED Voltage		V _{F OFF}	0.5	1		V
Output	On-Resistance	I _F =10mA, I _L =Rating	R _{ON}		110	200	Ω
	Drain to Drain (tested within 1 sec.)	I _F =10mA, I _L <5mA			180	300	
	Off-State Leakage Current	V _L = 1500V	I _{LEAK}			10	μA
	Output Capacitance	V _L =0V, f=1MHz	C _{OUT}		83		pF
Trans- mission	Turn-On Time	I _F =10mA, I _L =Rating	t _{ON}		0.2	1	ms
	Turn-Off Time	I _F =10mA, I _L =Rating	t _{OFF}		0.04	0.5	ms
Coupled	I/O Insulation Resistance		R _{I/O}	10 ¹⁰			Ω
	I/O Capacitance	f=1MHz	C _{I/O}		1.3		pF

PIN DESCRIPTION AND PART NUMBER

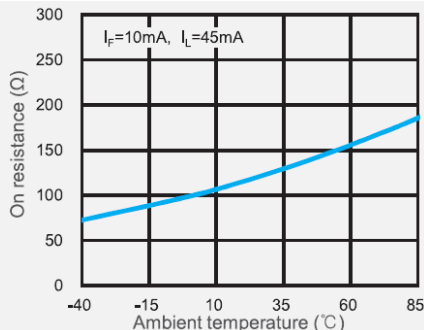
Circuit Diagram	Pin Description	Part No.	Package	Packing
	1 Anode (+) ■ LED 2 Cathode (-) ■ LED 3 NC 4,6 Drain ■ MOSFET 5 Source ■ MOSFET	AA40 AA40F AA40F-R1	DIP-6 SMD-6 SMD-6	Tube (50pcs) Tube (50pcs) Reel (1 000pcs)

REFERENCE DATA

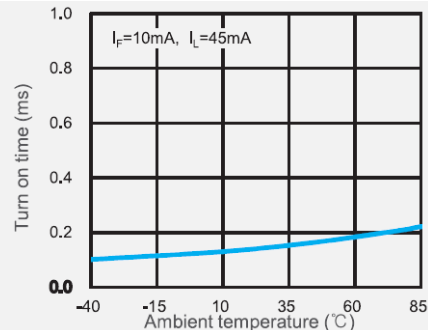
Load current vs. ambient temp.



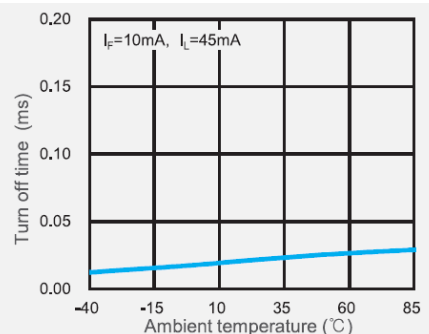
On resistance vs. ambient temp.



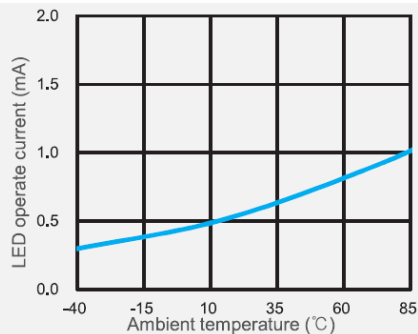
Turn on time vs. ambient temp.



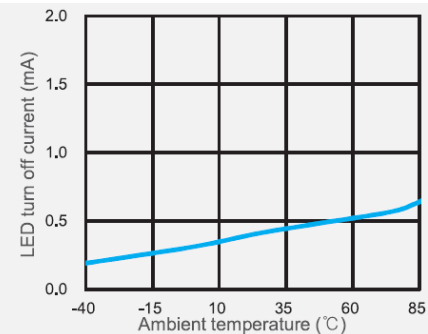
Turn off time vs. ambient temp.



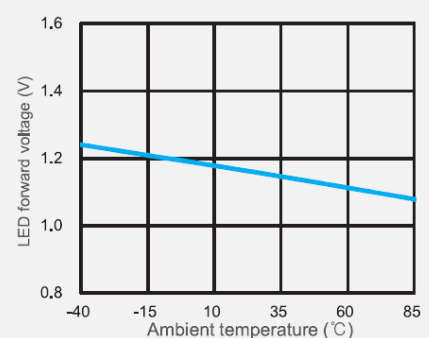
LED operate current vs. ambient temp



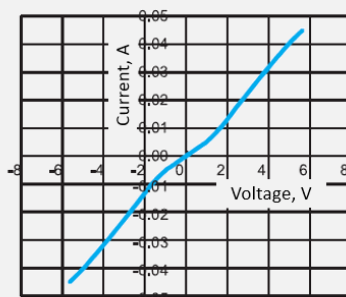
LED turn off current vs. ambient temp.



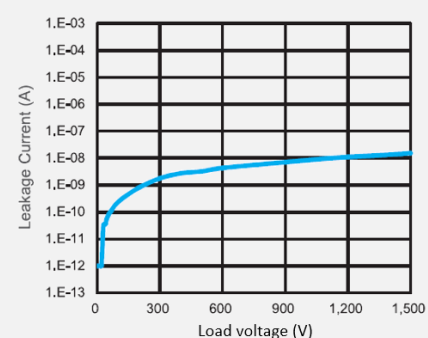
Load forward voltage vs. ambient temp.



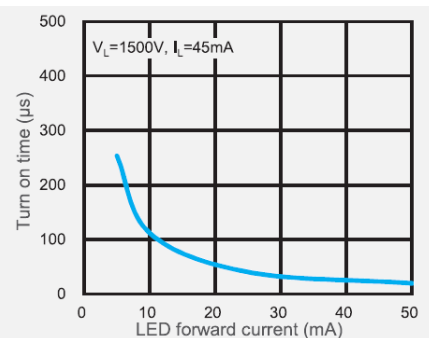
Current vs. voltage characteristics of output at MOS portion



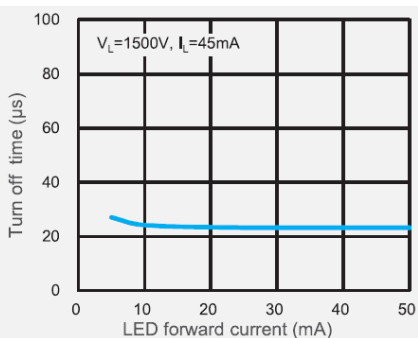
Off state leakage current vs. load voltage



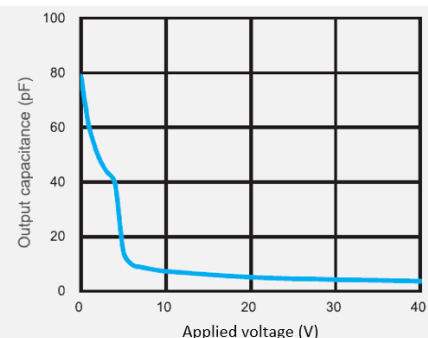
Turn on time vs. LED forward current



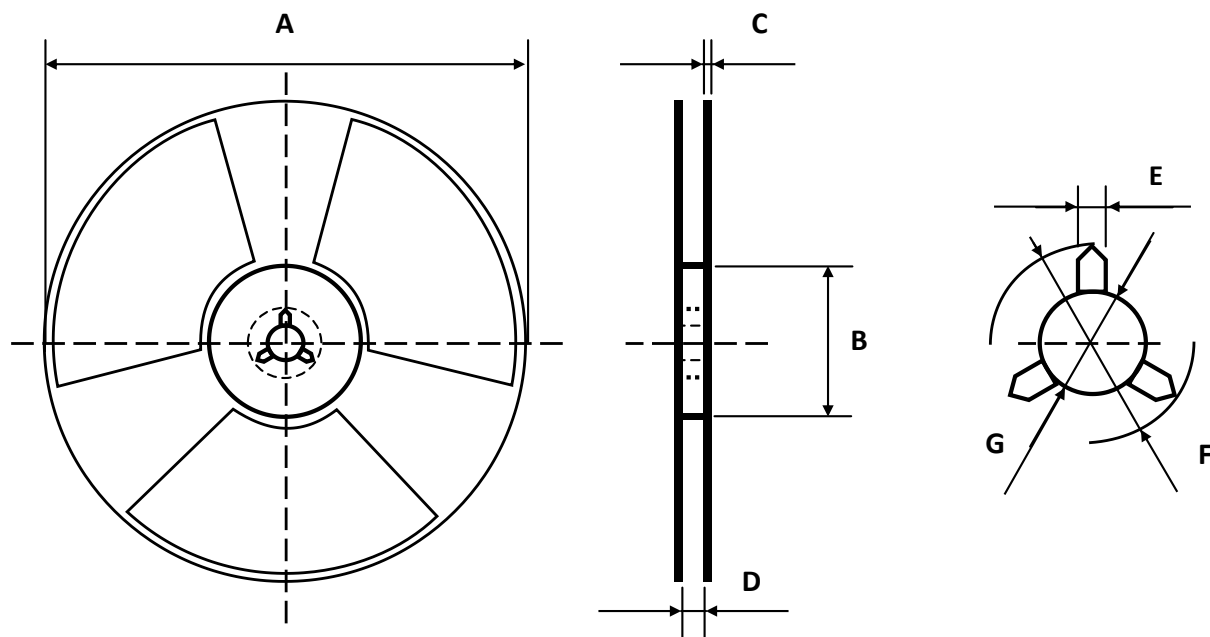
Turn off time vs. LED forward current



Output capacitance vs. applied voltage

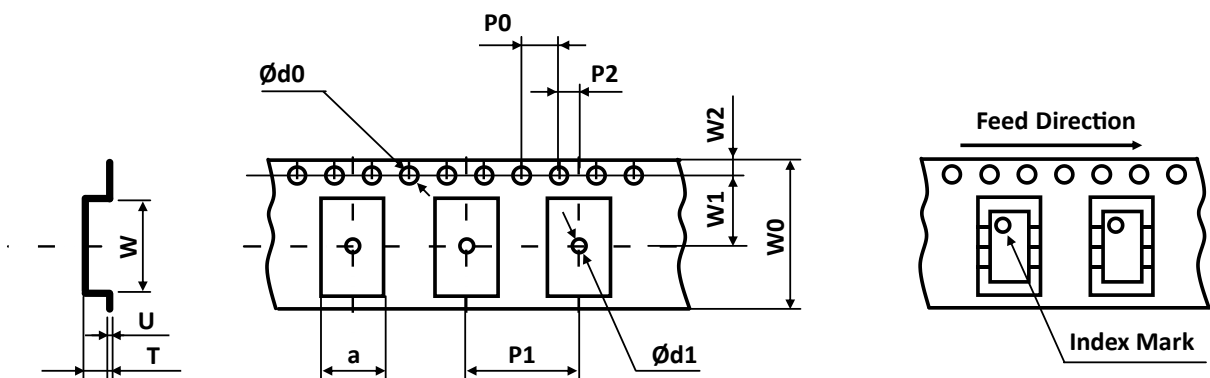


REEL DIMENSIONS ▲ All dimensions in mm



Size	A	B	C	D	E	F	G
SMD-6	380	80	2.2	17	2	13	21

TAPE DIMENSIONS ▲ All dimensions in mm



Size	W	U	T	a	Ød0	Ød1	P0	P1	P2	W0	W1	W2
SMD-6	9.15	0.3	4.45	10.4	1.5	1.5	4	16	2	16	11.5	1.75

PACKING QUANTITIES

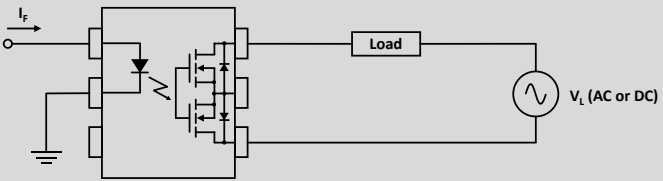
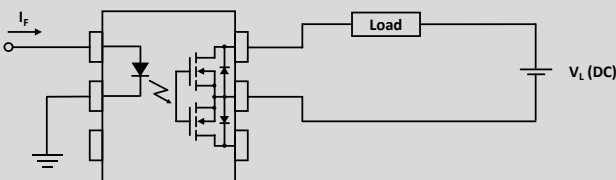
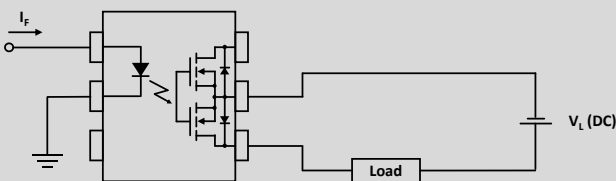
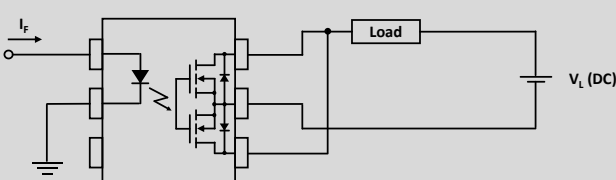
Tape and Reel Packing	PCS/Reel
SMD-6	1 000

Tube Packing	PCS/Tube	Tubes/Box	Units/Box
DIP-6	50	30	1 500

STORAGE AND HANDLING CONDITIONS

ESD level	Floor life	Conditions	MSL
HBM class 2	Unlimited	$T_A < 30^{\circ}\text{C}$, RH < 85%	1

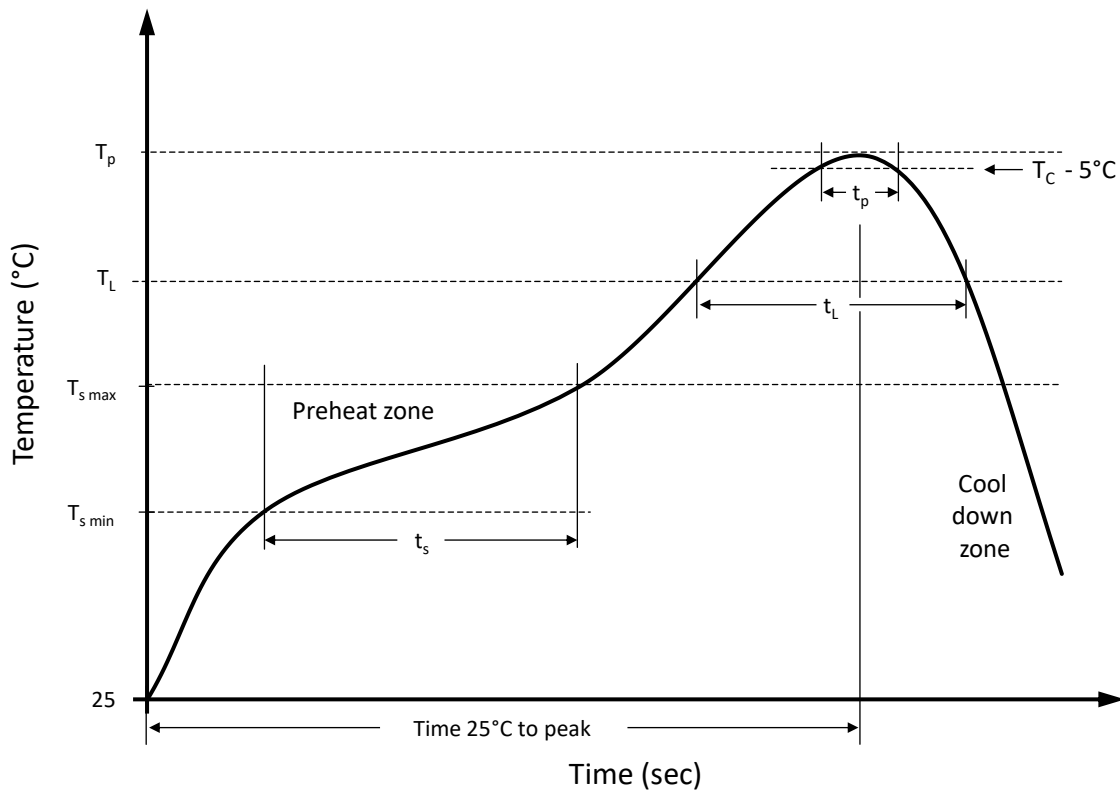
LOAD CONNECTING METHOD

Type	Load	Connection	Feature
6 pins	A AC or DC		Control bi-directional signal
	B DC		On-resistance is 1/2 of A-connection 2-Make-contacts (Source Common)
			
	C DC		On-Resistance is 1/2 of B-connection

CONTINUAL DC BIAS

In case of a continual DC bias is applied between outputs, the output MOSFET may deteriorate due to the voltage. Please verify operation of the actual design before using, or contact MGT.

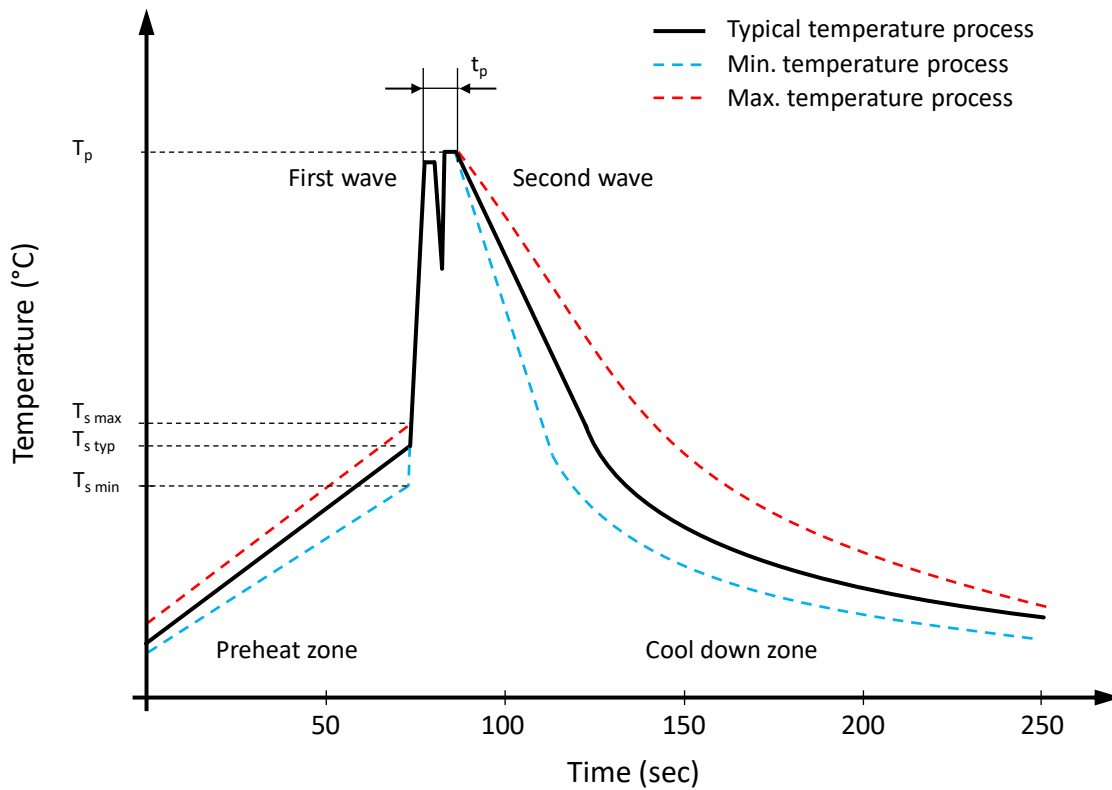
RECOMMENDED REFLOW SOLDERING PROFILE ▲ SMD PACKAGE



Recommended reflow soldering conditions ▲ Refer to JEDEC J-STD-020E

Profile Features		Sn-Pb Eutetic Assembly	Pb-Free Assembly
Preheat temperature min.	$T_{s \min}$	100 °C	150 °C
Preheat temperature max.	$T_{s \max}$	150 °C	200 °C
Preheat time t_s from $T_{s \min}$ to $T_{s \max}$	t_s	120 seconds	120 seconds
Ramp-up rate (T_L to T_p)		max. 3 °C/second	max. 3 °C/second
Liquidous temperature	T_L	183 °C	217 °C
Time t_L maintained above T_L	t_L	150 seconds max.	60 seconds max.
Peak package body temperature	T_p	235°C	260°C
Timeframe of within 5°C below and up to max actual peak body temperature	t_p	20 seconds max.	30 seconds max.
Ramp-down rate (T_L to T_p)		max. 6 °C/second	max. 6 °C/second
Time 25°C to peak temperature		max. 6 minutes	max. 8 minutes

RECOMMENDED WAVE SOLDERING PROFILE ▲ THT PACKAGE



Classification wave soldering profile ▲ Refer to EN 61760-1: 2006

Profile Features		Value ▲ Sn-Pb Assembly	Value ▲ Pb-free Assembly
Preheat temperature min.	$T_{s \min}$	100 °C	100 °C
Preheat temperature typical	$T_{s \text{ typ}}$	120 °C	120 °C
Preheat temperature max.	$T_{s \max}$	130 °C	130 °C
Preheat time t_s from $T_{s \min}$ to $T_{s \max}$	t_s	70 seconds	70 seconds
Peak temperature	T_p	235 °C to 260 °C	245 °C to 260 °C
Time of actual peak temperature	t_p	Max. 10 seconds Max. 5 second each wave	Max. 10 seconds Max. 5 second each wave
Ramp-down rate min.		~ 2 °C/second	~ 2 °C/second
Ramp-down rate typical		~ 3.5 °C/second	~ 3.5 °C/second
Ramp-down rate max.		~ 5 °C/second	~ 5 °C/second
Time 25°C to 25°C		4 minutes	4 minutes

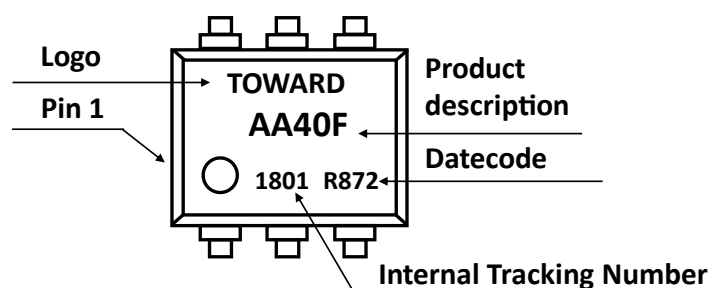
PRODUCT CODE

Example: AA40F series ▲ 1 Form A ▲ 1500V ▲ SMD-6 ▲ Tape & Reel

AA		40		-		F		R1	
Package		Series		Special Suffix		Type		Packing	
AA	6 Pin ▲ 1 Form A	40	1500V	Blank H	Standard High Insulation	Blank F	DIP SMD	Blank R1	Tube Reel

PRODUCT MARKING

Example: AA40F series ▲ 1 Form A ▲ 1500V ▲ SMD-6 ▲ Tape & Reel



DATE CODE

Example: R872

R		8		7		2	
Material Characteristics		Year		Month		Week of the Month	
R	RoHS compliant	8	2018	1	Jan	1	1 st
		9	2019	2	Feb		2 nd
		A	2020	3	Mar		3 rd
		B	2021	4	Apr		4 th
H	Halogen free	C	2022	5	May	2	1 st
			2 nd
		G	2026	12	Dec		3 rd
							4 th

RELIABILITY TESTS ▲ STANDARD

Standard: JESD22-A

No.	Test	Test Specification	Test Standard	Test Limits
1	Moisture Sensitivity Level Test	Bake condition: Temperature: 125°C; Duration 24 hours Soak condition: Temperature: 30°C; Humidity: 60% RH Duration 192 hours Reflow condition: Peak temperature: 260°C Duration: 3 cycles	JESD22-A113H	No abnormal phenomenon was found. Functional test passed.
2	High Temperature Storage Test	Temperature: 150°C Duration: 500 hours	JESD22-A103E	No abnormal phenomenon was found. Functional test passed.
3	Temperature Cycling Test	Temperature range: -55°C to +125°C -55°C for 30 minutes +125°C for 30 minutes Duration: 100 cycles with 1 cycle = 70 minutes	JESD22-A104E	No abnormal phenomenon was found. Functional test passed.
4	Low Temperature Storage Test	Temperature: -40°C Duration: 500 hours	JESD22-A119E	No abnormal phenomenon was found. Functional test passed.
5	Temperature & Humidity Storage Test	Temperature: 85°C Humidity: 85% RH Duration: 500 hours	JESD22-A101D	No abnormal phenomenon was found. Functional test passed.
6	Highly Accelerated Temperature and Humidity Stress Test	Temperature: 130°C Humidity: 85% RH Duration: 96 hours	JESD22-A-118B	No abnormal phenomenon was found. Functional test passed.

REVISION TABLE

Revision	Date	Status	Notes
001	01/10/2021	Initial release	Initial publication

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